

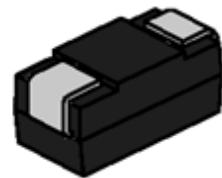


P4200TB TSS

Rev. 1.1

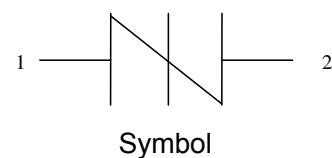
DESCRIPTION:

P4200TB is a type of semiconductor component. It is designed to protect baseband equipment from damaging overvoltage transients.



FEATURES:

- ✧ Low profile package.
- ✧ Low on-state voltage.
- ✧ Excellent capability of absorbing transient surge.
- ✧ Quick response to surge voltage (ns Level).
- ✧ Eliminates overvoltage caused by fast rising transients.
- ✧ Moisture sensitivity level: Level 1.
- ✧ Non degenerative.



SMA

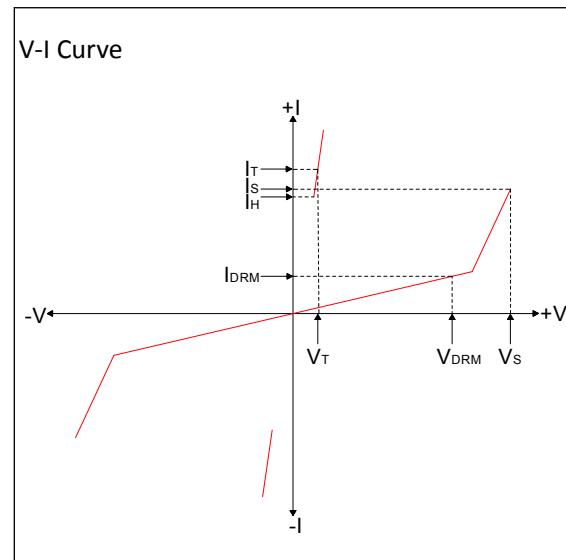
Symbol

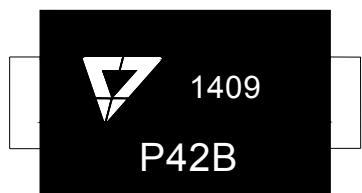
ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Storage temperature range	T_{STG}	-60 to +150	°C
Operating junction temperature range	T_J	-40 to +125	°C
Repetitive peak pulse current@10/1000μs	I_{PP}	80	A

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$)

Symbol	Parameter
V_{DRM}	Peak off-state voltage
I_{DRM}	Off-state current
V_s	Switching voltage
I_s	Switching current
V_T	On-state voltage
I_T	On-state current
I_H	Holding current
C_O	Off-state capacitance



MARKING

P42B : Device Marking Code
1409: In ninth week, 2014

ELECTRICAL CHARACTERISTICS (T_A=25°C, continued)

Part Number	I _{DRM} @V _{DRM}		V _s ^① @I _s		V _T @I _T		I _H	C _O ^②	Marking
	μA	V	V	mA	V	A	mA	pF	
	max		max	max	max	max	max	max	
P4200TB	5	400	520	800	4	2.2	100	35	P42B

① Vs is measured at 100kV/s

② Off-state capacitance is measured in V_{DC}=2V, V_{RMS}=1V, f=1MHz

SURGE RATINGS

Series	I _{PP} (A) min			
	2/10μs	8/20μs	10/360μs	10/1000μs
B	250	250	125	80

ORDERING INFORMATION

P	420	0	T	B	Surge ratings:4KV(10/700μs)
Series code P: SIDAC					Package type:SMA
					0: Bi-direction

SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{s(\min)}$)	+150 °C
	-Temperature Max($T_{s(\max)}$)	+200 °C
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L)to peak)		3 °C/sec. Max
$T_{s(\max)}$ to T_L - Ramp-up Rate		3 °C/sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217 °C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5) °C
Time within 5 °C of actual Peak Temp (t_p)		30secs.Max
Ramp-down Rate		6 °C/sec. Max
Time 25 °C to Peak Temp (T_p)		8 min. Max
Do not exceed		+260 °C

FIG.1: $tr \times td$ pulse waveform

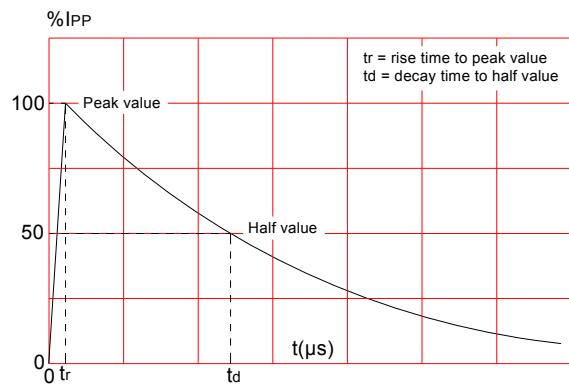


FIG.3: Normalized Vs change vs. junction temperature

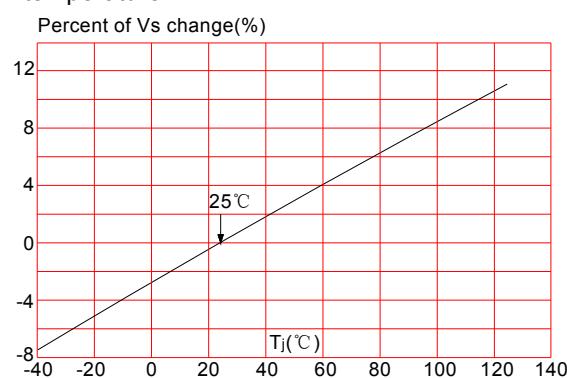


FIG.2: Reflow condition

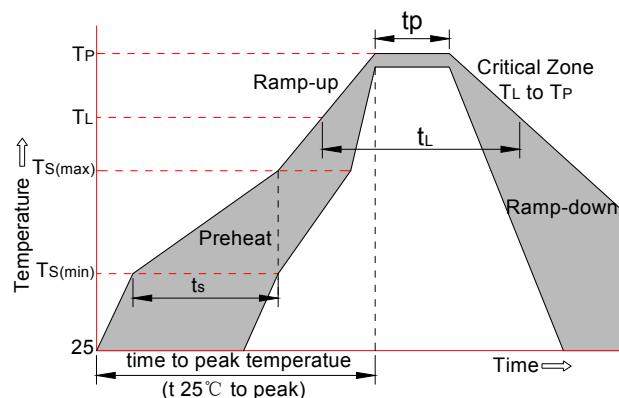
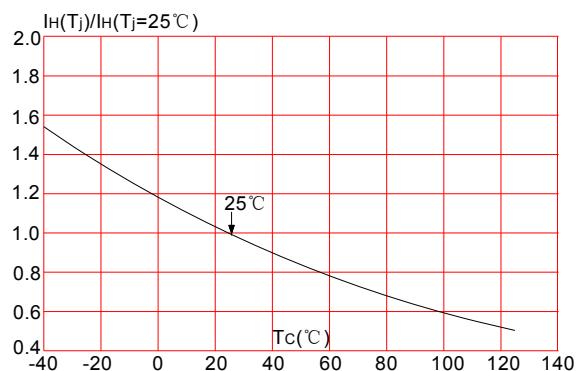
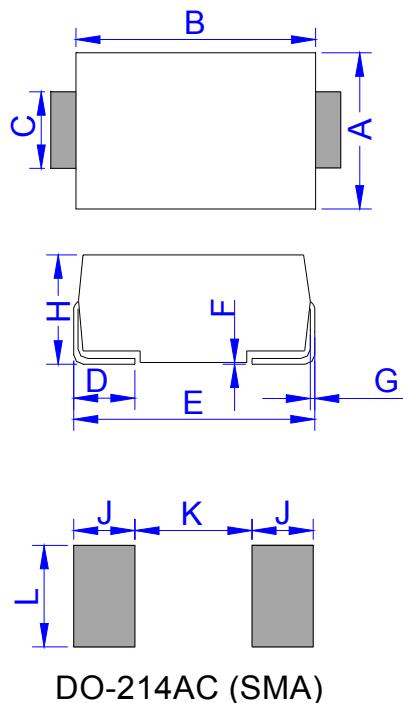


FIG.4: Normalized DC holding current vs. case temperature

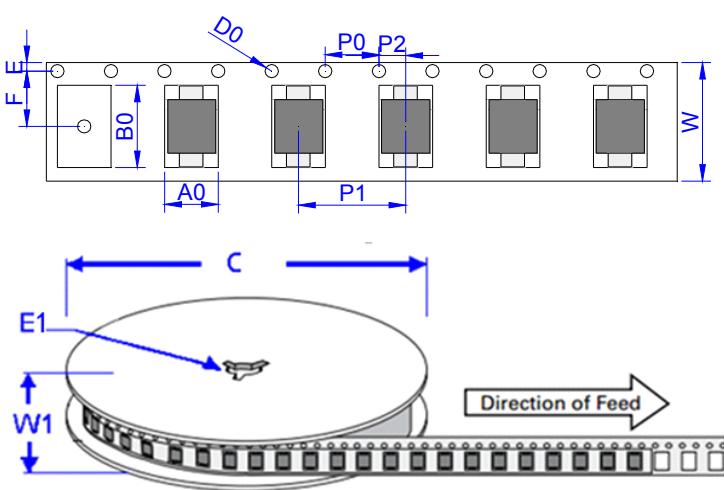


PACKAGE MECHANICAL DATA



Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.60	3.00	0.102	0.118
B	4.15	4.65	0.163	0.183
C	1.25	1.65	0.049	0.065
D	0.95	1.52	0.037	0.060
E	4.90	5.30	0.193	0.209
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.00	2.44	0.079	0.096
J	2.00		0.079	
K		2.30		0.091
L	1.80		0.071	

TAPE AND REEL SPECIFICATION-SMA



Ref.	Dimensions	
	Millimeters	Inches
A0	2.79 ± 0.3	0.110 ± 0.012
B0	5.33 ± 0.3	0.210 ± 0.012
C	330.0	13.0
D0	1.55 ± 0.1	0.061 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524 ± 0.012
F	5.5 ± 0.2	0.217 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	12.0 ± 0.2	0.472 ± 0.008
W1	15.7 ± 2.0	0.618 ± 0.079

PART No.	UNIT WEIGHT (g/PCS) typ.	REEL (PCS)	PER CARTON (PCS)	DESCRIPTION
P4200TB	0.069	7,500	120,000	13 inch reel pack

Information furnished in this document is believed to be accurate and reliable. However, Jiangsu JieJie Microelectronics Co.,Ltd assumes no responsibility for the consequences of use without consideration for such information nor use beyond it. Information mentioned in this document is subject to change without notice, apart from that when an agreement is signed, Jiangsu JieJie complies with the agreement. Products and information provided in this document have no infringement of patents. Jiangsu JieJie assumes no responsibility for any infringement of other rights of third parties which may result from the use of such products and information. This document is the 1.1st version which is made in 6-July-2021. This document supersedes and replaces all information previously supplied.

 is a registered trademark of Jiangsu JieJie Microelectronics Co.,Ltd.
Copyright©2021 Jiangsu JieJie Microelectronics Co.,Ltd. Printed All rights reserved.